



### **Key Parameters**

 $\begin{array}{lll} V_{DRM} \, / \, V_{RRM} &= 3600 V \\ I_{T(AV)} &= 321 A \\ I_{TSM} &= 6000 A \\ V_{T(TO)} &= 1.15 V \\ r_{T} &= 0.8 m \Omega \end{array}$ 

#### **Features**

- Full blocking capability over wide temperature range
- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Pressure contacts technology for high reliability
- UL Recognized, file no. E505556

### **Applications**

- Power Supplies
- DC motor control
- Controlled Rectifiers
- AC switch

#### **Ordering Information**

MS	TD	321	K	36
Fixed code	TD- Thyristor- Diode Module	Current Code	Technology K = Pressure Contact Technology	Voltage Code Code X 100 = V <sub>DRM</sub> /V <sub>RRM</sub>
Order Code, MS TD321K36 : 3600V VDRM VRRM, Thyristor-Diode Module				

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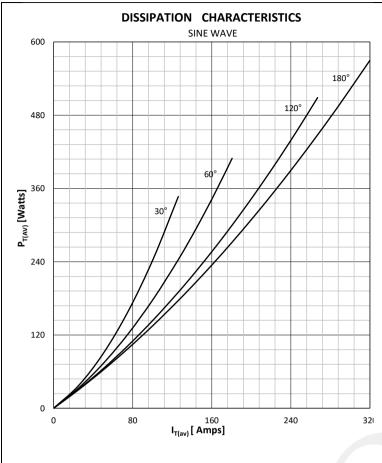
# Technical Information Thyristor / Diode Modules

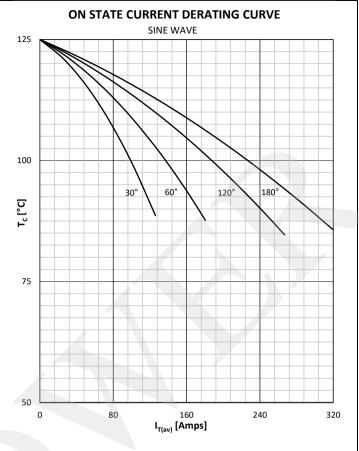
### **MS TD321**

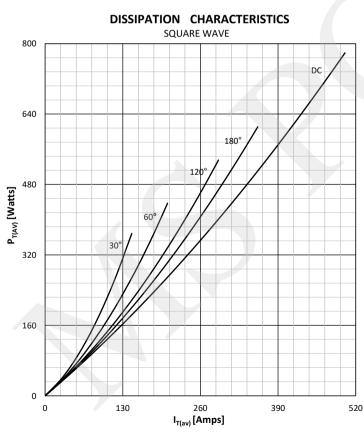


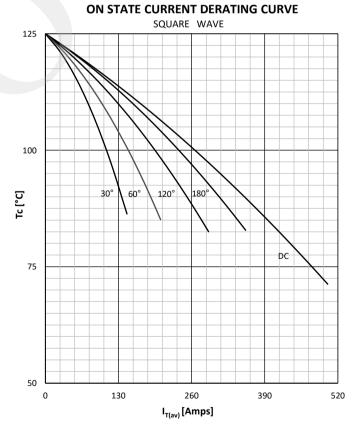
Symbol	Characteristic	Conditions	Tj [°C]	Value	Unit
BLOCKI	NG				
V RRM	Repetitive peak reverse voltage		125	3000 - 3600	V
V RSM	Non-repetitive peak reverse voltage		125	3100 - 3700	V
V DRM	Repetitive peak off-state voltage		125	3000 - 3600	V
I RRM	Repetitive peak reverse current	V= V RRM	125	200	mA
I DRM	Repetitive peak off-state current	V= V DRM	125	200	mA
CONDUC	CTING				
I T (AV)	Mean on state current	180° sin ,50 Hz, T <sub>c</sub> =85°C		321	Α
I RMS	RMS on-state current			502	A
	Surge on-state current	Sine wave, 10 ms	25	6000	Α
ITSM		Without reverse voltage	125	5500	Α
		0: 10	25	180 x 10 <sup>3</sup>	A <sup>2</sup> s
l² t		Sine wave, 10 ms Without reverse voltage	125	151 x 10 <sup>3</sup>	A²s
Vт	On-state voltage	On-state current = 785A	25	2.20	V
		OIPState Cullent = 700A	125	1.15	V
V T(TO)	Threshold voltage				
rт	On-state slope resistance		125	0.8	mΩ
WITCH	ING				
di/dt	Critical rate of rise of on-state current	Non-repetitive f=1Hz, $I_{GM}$ =2.0A, $di_G/dt$ >1.0A/ $\mu$ s, $I_{TM}$ =2 $I_{TAV}$ , $V_D$ =67% $V_{DRM}$	125	400	A/µs
dv/dt	Critical rate of rise of off-state voltage	$V_{DR} = 67\%V_{DRM}$	125	1000	V/µs
SATE					
I gt	Gate trigger current	V <sub>D</sub> =6V	25	250	mA
$V_{gt}$	Gate trigger voltage	V <sub>D</sub> =6V	25	3.0	V
I <sub>H</sub>	Holding current	V <sub>D</sub> =6V, gate open circuit	25	300	mA
ΙL	Latching current	V <sub>D</sub> =6V	25	1500	mA
IOUNTI	NG				
R th(j-c)	Thermal impedance, sin 180°	Junction to case, per arm per module		0.068 0.034	°C/W
R th(j-c)	Thermal impedance, rec120°	Junction to case, per arm per module		0.078 0.039	°C/W
R th(c-h)	Thermal impedance	Case to heatsink, per arm per module		0.02 0.01	°C/W
Тj	Max. junction temperature			125	°C
T stg	Storage temperature			-40 150	°C
V <sub>ISOL</sub>	Insulation test voltage,RMS	F=50Hz, 1min		3.0	KV
M1	Mounting torque			6 ± 15%	Nm
M2	Terminal connection torque			12 ± 15%	Nm
W	Weight (Approx.)			1450	gm
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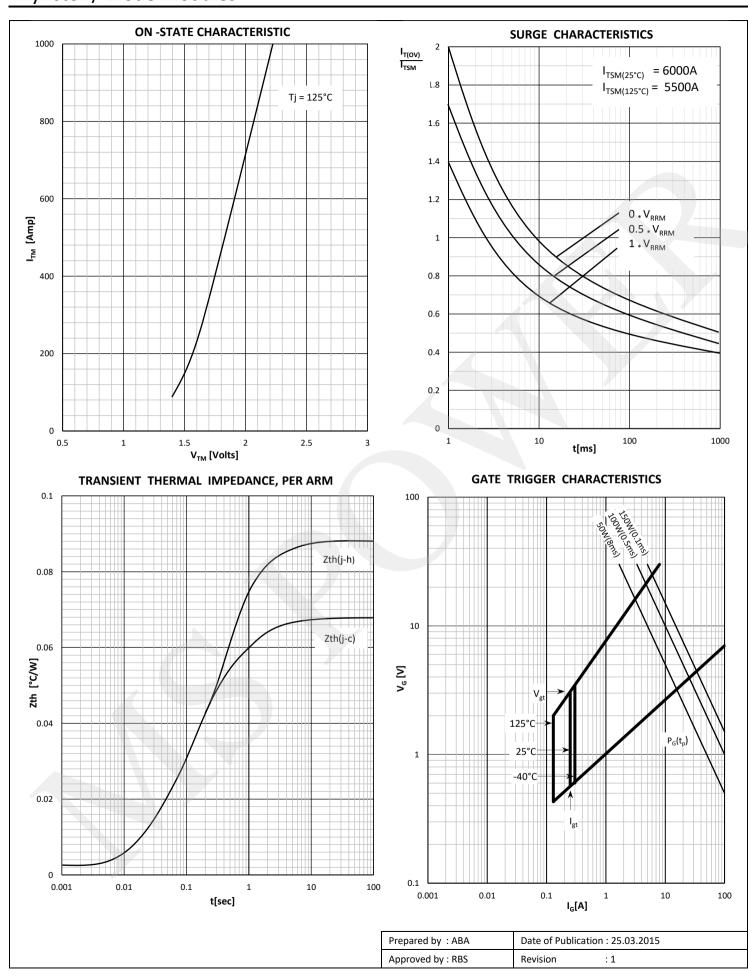






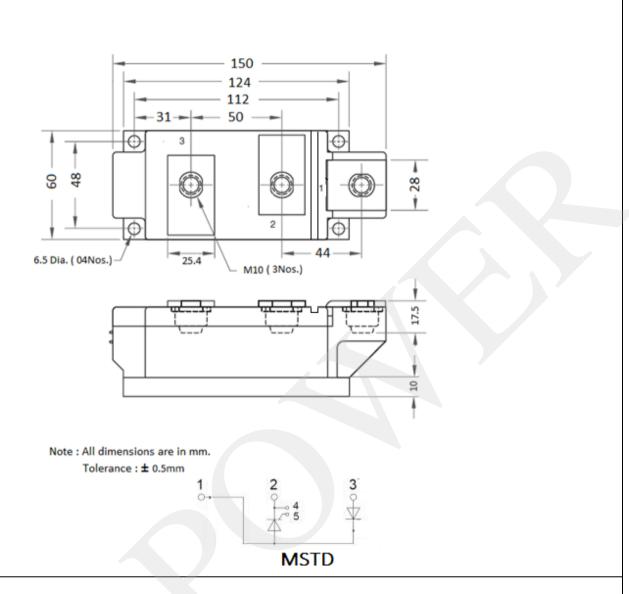
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### **MS TD321**



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